NSN 5961-01-013-0682

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-013-0682 **Inclosure Material:** Metal **Overall Length:** 0.245 inches **Overall Height:** 0.245 inches **Overall Width:** 0.505 inches **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak **Current Rating Per Characteristic:** 30.00 amperes forward current, average **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 1 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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